

	<h2 style="color: red;">FQD7P06TM_NB82050</h2>
	<p>Hersteller-Teilenummer: FQD7P06TM_NB82050</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 60V 5.4A DPAK</p> <p>Datenblätter:  FQD7P06TM_NB82050.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 32363 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQD7P06TM_NB82050
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 60V 5.4A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	2.5W (Ta), 28W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	5.4A (Tc)
Rds On (Max) @ Id, Vgs	451 mOhm @ 2.7A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.2nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	295pF @ 25V
Verpackung	Tape & Reel (TR)



































FQD7P06TM_NB82050 ist neu im Original, Suche FQD7P06TM_NB82050 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD7P06TM_NB82050 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD7P06TM_NB82050: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQD7P20TF Fairchild/ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>	 <p>FQD7P06TM Fairchild/ON Semiconductor MOSFET P-CH 60V 5.4A DPAK</p>	 <p>FQD7P06TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 5.4A DPAK</p>	 <p>FQD7P06TM_F080 AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 5.4A DPAK</p>
 <p>FQD7P20TF AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>	 <p>FQD7P20TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 5.7A DPAK</p>	 <p>FQD7P20 Original FQD7P20 Original</p>	 <p>FQD7P10TF FAI FQD7P10TF FAI</p>

heiße Teile

Mehr

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|---|---|---|--|--|
|  FQD6P25TM |  FQD6P25TM |  FQD7N10L |  FQD7N10LTF |  FQD7N10LTF |
|  FQD7N10LTM |  FQD7N10LTM |  FQD7N10TF |  FQD7N10TM |  FQD7N10TM |
|  FQD7N20L |  FQD7N20LTF |  FQD7N20LTF |  FQD7N20LTM |  FQD7N20LTM |
|  FQD7N20TF |  FQD7N20TF |  FQD7N20TM |  FQD7N20TM |  FQD7N30TM |
|  FQD7N30TM |  FQD7P06TF |  FQD7P06TF |  FQD7P06TM |  FQD7P06TM |
|  FQD7P06TM_F080 |  FQD7P06TM_F080 |  FQD7P06TM_NB82050 |  FQD7P10TF |  FQD7P20TF |
|  FQD7P20TF |  FQD7P20TM |  FQD7P20TM |  FQD7P20TM_F080 |  FQD7P20TM_F080 |
|  FQD8P10TF |  FQD8P10TF |  FQD8P10TF_NB82052 |  FQD8P10TF_NB82052 |  FQD8P10TM |
|  FQD8P10TM |  FQD8P10TM_ |  FQD8P10TM_F080 |  FQD8P10TM_F080 |  FQD8P10TM_F085 |
|  FQD8P10TM_SB82052 |  FQD8P10TM_SB82052 |  FQD9N08L |  FQD9N25TM |  FQD9N25TM |

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